

SA52-11LEWA HIGH EFFICIENCY RED

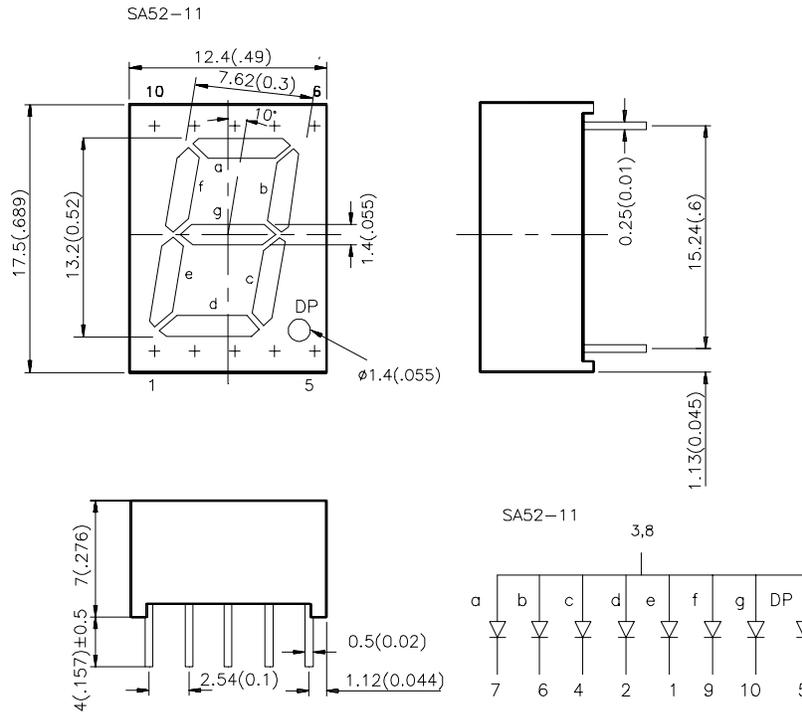
Features

- LOW CURRENT $I_F=2\text{mA}$ OPERATING
- 0.52 INCH DIGIT HEIGHT.
- LOW CURRENT OPERATION.
- EXCELLENT CHARACTER APPEARANCE.
- EASY MOUNTING ON P.C. BOARDS OR SOCKETS.
- I.C. COMPATIBLE.
- CATEGORIZED FOR LUMINOUS INTENSITY,
YELLOW AND GREEN CATEGORIZED FOR COLOR.
- MECHANICALLY RUGGED.
- STANDARD : GRAY FACE, WHITE SEGMENT.

Description

The High Efficiency Red source color devices are made with Gallium Arsenide Phosphide on Gallium Phosphide Orange Light Emitting Diode.

Package Dimensions & Internal Circuit Diagram



Notes:

1. All dimensions are in millimeters (inches), Tolerance is $\pm 0.25(0.01)$ unless otherwise noted.
2. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Iv (mcd) @ 2 mA		Description
		Min.	Typ.	
SA52-11LEWA	HIGH EFFICIENCY RED (GaAsP/GaP)	0.48	1.2	Common Anode, Rt. Hand Decimal

Electrical / Optical Characteristics at T_A=25°C

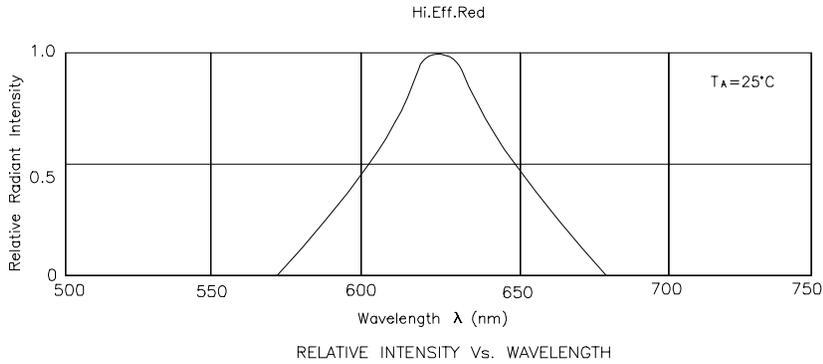
Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ_{peak}	Peak Wavelength	High Efficiency Red	625		nm	IF=2mA
λ_D	Dominate Wavelength	High Efficiency Red	627		nm	IF=2mA
$\Delta\lambda_{1/2}$	Spectral Line Halfwidth	High Efficiency Red	45		nm	IF=2mA
C	Capacitance	High Efficiency Red	15		pF	VF=0V;f=1MHz
V _F	Forward Voltage	High Efficiency Red	1.7	2.5	V	IF=2mA
I _r	Reverse Current	High Efficiency Red		10	uA	VR = 5V

Absolute Maximum Ratings at T_A=25°C

Parameter	High Efficiency Red	Units
Power dissipation	105	mW
DC Forward Current	30	mA
Peak Forward Current [1]	160	mA
Reverse Voltage	5	V
Operating/Storage Temperature	-40°C To +85°C	
Lead Soldering Temperature[2]	260°C For 5 Seconds	

Notes:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.
2. 4mm below package base.



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